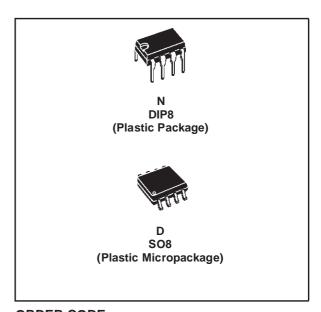


## TL072 TL072A - TL072B

## LOW NOISE J-FET DUAL OPERATIONAL AMPLIFIERS

- WIDE COMMON-MODE (UP TO V<sub>CC</sub><sup>+</sup>) AND DIFFERENTIAL VOLTAGE RANGE
- LOW INPUT BIAS AND OFFSET CURRENT
- LOW NOISE  $e_n = 15 \text{nV}/\sqrt{\text{Hz}}$  (typ)
- OUTPUT SHORT-CIRCUIT PROTECTION
- HIGH INPUT IMPEDANCE J-FET INPUT STAGE
- LOW HARMONIC DISTORTION: 0.01% (typ)
- INTERNAL FREQUENCY COMPENSATION
- LATCH UP FREE OPERATION
- HIGH SLEW RATE : 16V/µs (typ)



### **DESCRIPTION**

The TL072, TL072A and TL072B are high speed J–FET input dual operational amplifiers incorporating well matched, high voltage J–FET and bipolar transistors in a monolithic integrated circuit.

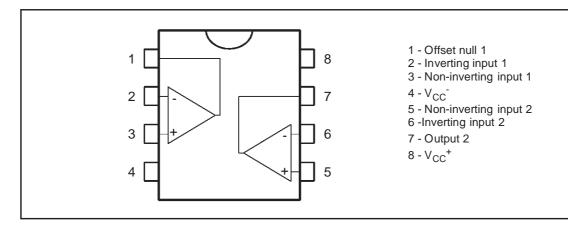
The devices feature high slew rates, low input bias and offset current, and low offset voltage temperature coefficient.

## **ORDER CODE**

Part Number	Temperature Range	Package					
Fait Number	Temperature Kange	N	D				
TL072M/AM/BM	-55°C, +125°C	•	•				
TL072I/AI/BI	-40°C, +105°C	•	•				
TL072C/AC/BC	0°C, +70°C	•	•				
Example: TL072CN							

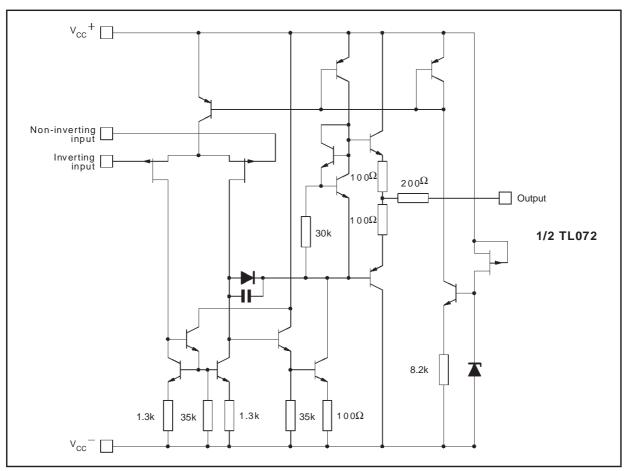
 ${f N}$  = Dual in Line Package (DIP)  ${f D}$  = Small Outline Package (SO) - also available in Tape & Reel (DT)

PIN CONNECTIONS (top view)



March 2001 1/10

### **SCHEMATIC DIAGRAM**



## **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	TL072M, AM, BM	TL072I, AI, BI	TL072C, AC, BC	Unit	
V <sub>CC</sub>	Supply voltage - note 1)		V			
Vi	Input Voltage - note <sup>2)</sup>	±15				
V <sub>id</sub>	Differential Input Voltage - note 3) ±30					
P <sub>tot</sub>	Power Dissipation	680				
	Output Short-circuit Duration - note 4)	Infinite				
T <sub>oper</sub>	Operating Free-air Temperature Range	-55 to +125 -40 to +105 0 to +70			°C	
T <sub>stg</sub>	Storage Temperature Range	-65 to +150				

All voltage values, except differential voltage, are with respect to the zero reference level (ground) of the supply voltages where the zero reference level is the midpoint between V<sub>CC</sub><sup>+</sup> and V<sub>CC</sub>.

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<sup>2.</sup> The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 volts, whichever is less.

<sup>3.</sup> Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.

The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded

### **ELECTRICAL CHARACTERISTICS**

 $V_{CC} = \pm 15V$ ,  $T_{amb} = +25^{\circ}C$  (unless otherwise specified)

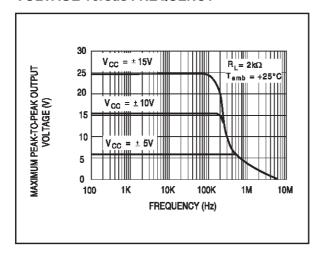
Symbol	Parameter		TL072I,M,AC,AI,AM, BC,BI,BM			TL072C		
		Min.	Тур.	Max.	Min.	Тур.	Max.	
V <sub>io</sub>	Input Offset Voltage ( $R_s = 50\Omega$ ) $T_{amb} = +25^{\circ}C \qquad TL072$ $TL072A$ $TL072B$ $T_{min} \leq T_{amb} \leq T_{max} \qquad TL072$ $TL072A$ $TL072A$		3 3 1	10 6 3 13 7		3	10	mV
DV	TL072B		40	5		40		1//00
DV <sub>io</sub>	Input Offset Voltage Drift		10			10		μV/°C
I <sub>io</sub>	Input Offset Current - note $^{1)}$ $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		5	100 4		5	100 10	pA nA
l <sub>ib</sub>	Input Bias Current -note 1 $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		20	200 20		20	200 20	pA nA
A <sub>vd</sub>	Large Signal Voltage Gain $(R_L = 2k\Omega, V_0 = \pm 10V)$ $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$	50 25	200		25 15	200		V/mV
SVR	Supply Voltage Rejection Ratio ( $R_S = 50\Omega$ ) $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$	80 80	86		70 70	86		dB
I <sub>CC</sub>	Supply Current, no load $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		1.4	2.5 2.5		1.4	2.5 2.5	mA
V <sub>icm</sub>	Input Common Mode Voltage Range	±11	+15 -12		±11	+15 -12		V
CMR	Common Mode Rejection Ratio ( $R_S = 50\Omega$ ) $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$	80 80	86		70 70	86		dB
I <sub>os</sub>	Output Short-circuit Current $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$	10 10	40	60 60	10 10	40	60 60	mA
±V <sub>opp</sub>	$\begin{array}{ccc} \text{Output Voltage Swing} & & & & \\ & T_{amb} = +25^{\circ}\text{C} & & & \text{RL} = 2k\Omega \\ & & & & \text{RL} = 10k\Omega \\ & T_{min} \leq T_{amb} \leq T_{max} & & & \text{RL} = 2k\Omega \\ & & & & \text{RL} = 10k\Omega \end{array}$	10 12 10 12	12 13.5		10 12 10 12	12 13.5		V
SR	Slew Rate ( $T_{amb} = +25^{\circ}C$ ) $V_{in} = 10V$ , $R_L = 2k\Omega$ , $C_L = 100pF$ , unity gain	8	16		8	16		V/µs
t <sub>r</sub>	Rise Time ( $T_{amb} = +25^{\circ}C$ ) $V_{in} = 20$ mV, $R_L = 2$ k $\Omega$ , $C_L = 100$ pF, unity gain		0.1			0.1		μs
K <sub>ov</sub>	Overshoot ( $T_{amb}$ = +25°C) $V_{in}$ = 20mV, $R_L$ = 2k $\Omega$ , $C_L$ = 100pF, unity gain		10			10		%
GBP	Gain Bandwidth Product ( $T_{amb}$ = +25°C) $V_{in}$ = 10mV, $R_L$ = 2k $\Omega$ , $C_L$ = 100pF, f= 100kHz	2.5	4		2.5	4		MHz
R <sub>i</sub>	Input Resistance		10 <sup>12</sup>			10 <sup>12</sup>		Ω

## TL072 - TL072A - TL072B

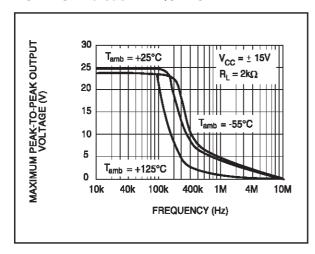
Symbol	Parameter	TL072I,M,AC,AI,AM, BC,BI,BM			TL072C			Unit
		Min.	Тур.	Max.	Min.	Тур.	Max.	
THD	Total Harmonic Distortion ( $T_{amb} = +25^{\circ}C$ ) $f = 1 \text{kHz}, R_L = 2 \text{k}\Omega, C_L = 100 \text{pF}, A_V = 20 \text{dB},$ $V_0 = 2 V_{pp}$		0.01			0.01		%
e <sub>n</sub>	Equivalent Input Noise Voltage $R_S = 100\Omega$ , $f = 1KHz$		15			15		n∨ √Hz
Øm	Phase Margin		45			45		degrees
V <sub>o1</sub> /V <sub>o2</sub>	Channel separation $A_V = 100$		120			120		dB

<sup>1.</sup> The input bias currents are junction leakage currents which approximately double for every 10°C increase in the junction temperature.

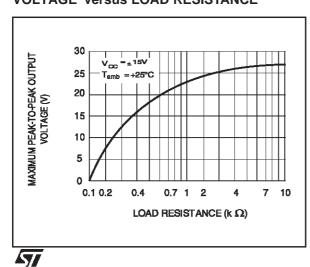
## MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREQUENCY



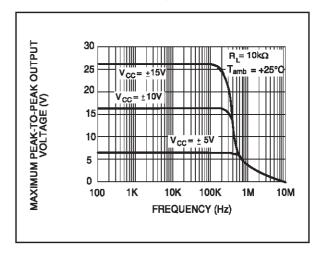
# MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREQUENCY



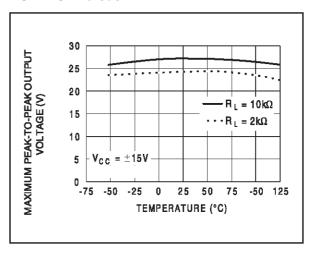
# MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus LOAD RESISTANCE



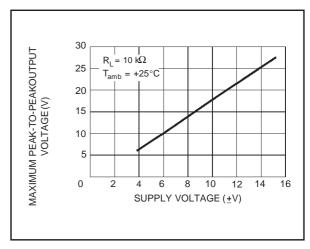
## MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREQUENCY



# MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREE AIR TEMP.

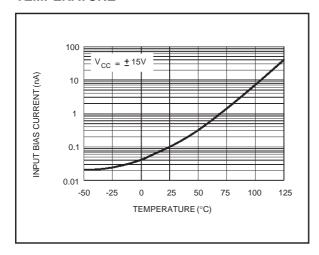


## MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus SUPPLY VOLTAGE

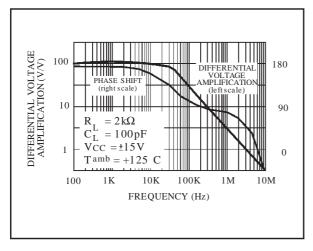


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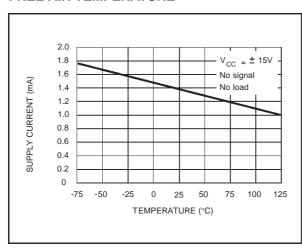
## INPUT BIAS CURRENT versus FREE AIR TEMPERATURE



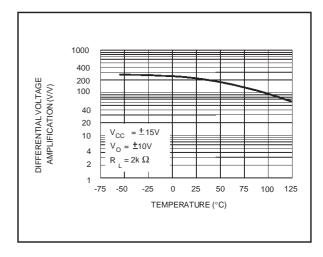
# LARGE SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT versus FREQUENCY



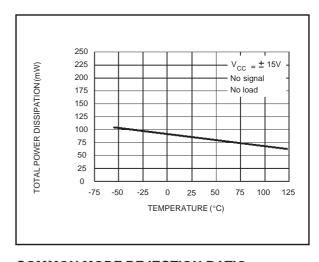
## SUPPLY CURRENT PER AMPLIFIER versus FREE AIR TEMPERATURE



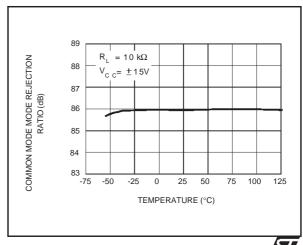
## LARGE SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION versus FREE AIR TEMP.



## TOTAL POWER DISSIPATION versus FREE AIR TEMPERATURE

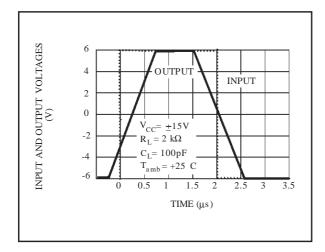


# COMMON MODE REJECTION RATIO versus FREE AIR TEMPERATURE

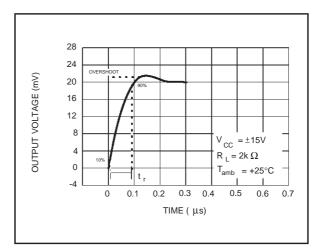


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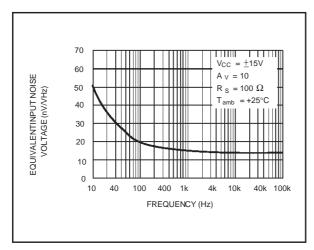
# VOLTAGE FOLLOWER LARGE SIGNAL PULSE RESPONSE



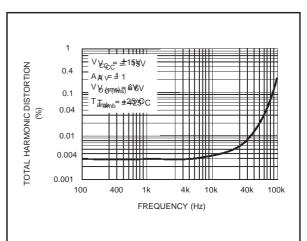
### **OUTPUT VOLTAGE versus ELAPSED TIME**



# EQUIVALENT INPUT NOISE VOLTAGE versus FREQUENCY



# TOTAL HARMONIC DISTORTION versus FREQUENCY



### PARAMETER MEASUREMENT INFORMATION

Figure 1 : Voltage Follower

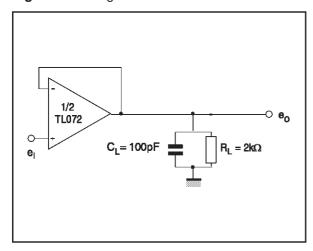
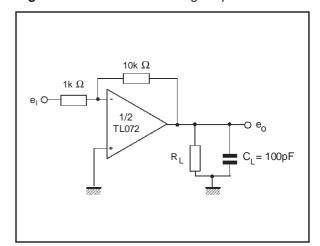
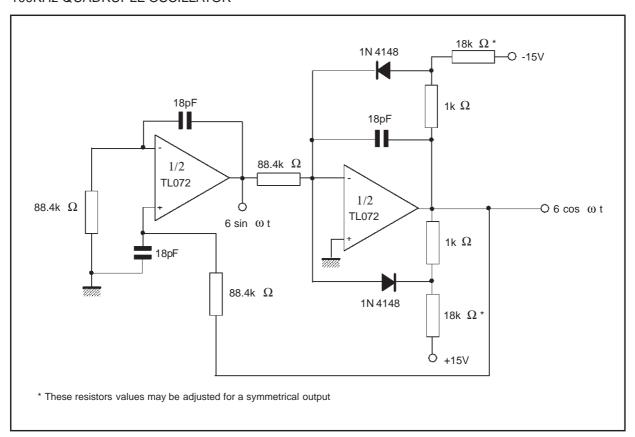


Figure 2: Gain-of-10 Inverting Amplifier



### **TYPICAL APPLICATIONS**

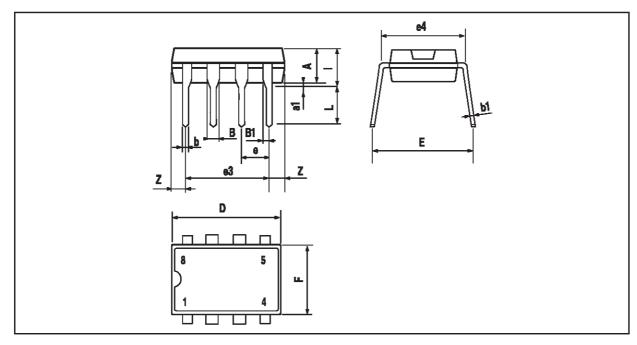
100KHz QUADRUPLE OSCILLATOR



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### PACKAGE MECHANICAL DATA

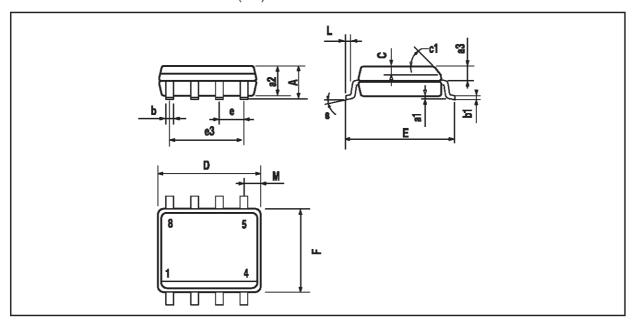
8 PINS - PLASTIC DIP



Dim		Millimeters		Inches				
Dim.	Min.	Тур.	Max.	Min.	Тур.	Max.		
А		3.32			0.131			
a1	0.51			0.020				
В	1.15		1.65	0.045		0.065		
b	0.356		0.55	0.014		0.022		
b1	0.204		0.304	0.008		0.012		
D			10.92			0.430		
E	7.95		9.75	0.313		0.384		
е		2.54			0.100			
e3		7.62			0.300			
e4		7.62			0.300			
F			6.6			0260		
i			5.08			0.200		
L	3.18		3.81	0.125		0.150		
Z			1.52			0.060		

### **PACKAGE MECHANICAL DATA**

8 PINS - PLASTIC MICROPACKAGE (SO)



Dim	Millimeters			Inches			
Dim.	Min.	Тур.	Max.	Min.	Тур.	Max.	
А			1.75			0.069	
a1	0.1		0.25	0.004		0.010	
a2			1.65			0.065	
a3	0.65		0.85	0.026		0.033	
b	0.35		0.48	0.014		0.019	
b1	0.19		0.25	0.007		0.010	
С	0.25		0.5	0.010		0.020	
c1			45°	(typ.)			
D	4.8		5.0	0.189		0.197	
E	5.8		6.2	0.228		0.244	
е		1.27			0.050		
e3		3.81			0.150		
F	3.8		4.0	0.150		0.157	
L	0.4		1.27	0.016		0.050	
M			0.6			0.024	
S	8° (max.)						

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